MICROCHIP

MIC4827

Low Input Voltage, 180 V_{PP} Output Voltage, EL Driver

Features

- 1.8V to 5.5V DC Input Voltage
- 180 V_{PP} Regulated AC Output Waveform
- Independently Adjustable EL Lamp Frequency
- Independently Adjustable Boost Converter Frequency
- 0.1 µA Shutdown Current

Applications

- LCD Panel Backlight
- Cellular Phones
- PDAs
- Pagers
- Calculators
- Remote Controls
- Portable Phones

General Description

The MIC4827 is a high output voltage, DC to AC converter, designed for driving EL (Electroluminescent) lamps. The device operates from an input voltage range of 1.8V to 5.5V, making it suitable for 1-cell Li Ion and 2-cell or 3-cell alkaline/NiCad/NiMH battery applications. The MIC4827 converts a low voltage DC input to a 180 V_{PP} AC output signal that drives the EL lamp.

The MIC4827 is comprised of two stages: a boost stage, and an H-bridge, lamp driver, stage. The boost stage steps the input voltage up to +90V. The H-bridge stage then alternately switches the +90V output to each terminal of the EL lamp, thus creating a 180 V_{PP} AC signal to drive the EL lamp and generate light.

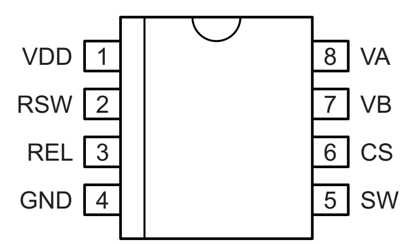
The MIC4827 features separate oscillators for the boost and H-bridge stages. External resistors independently set the operating frequency of each stage. This flexibility allows the EL lamp circuit to be optimized for maximum efficiency and brightness.

The MIC4827 uses a single inductor and a minimum number of external components, making it ideal for portable, space sensitive applications.

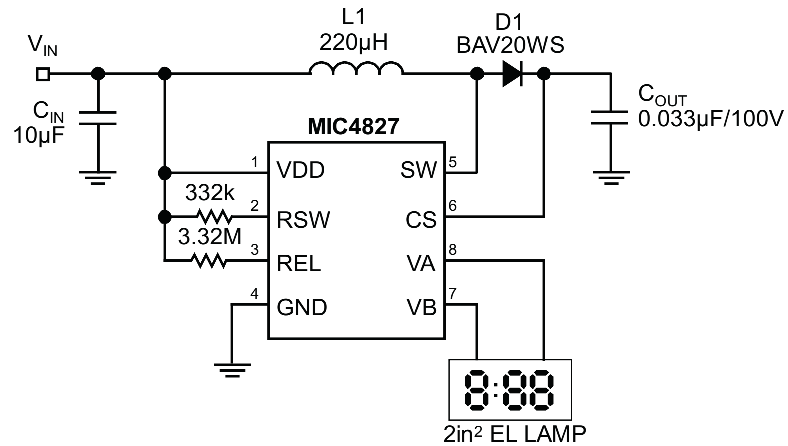
The MIC4827 is available in an 8-lead MSOP package with an ambient temperature range of –40°C to +85°C.

Package Type

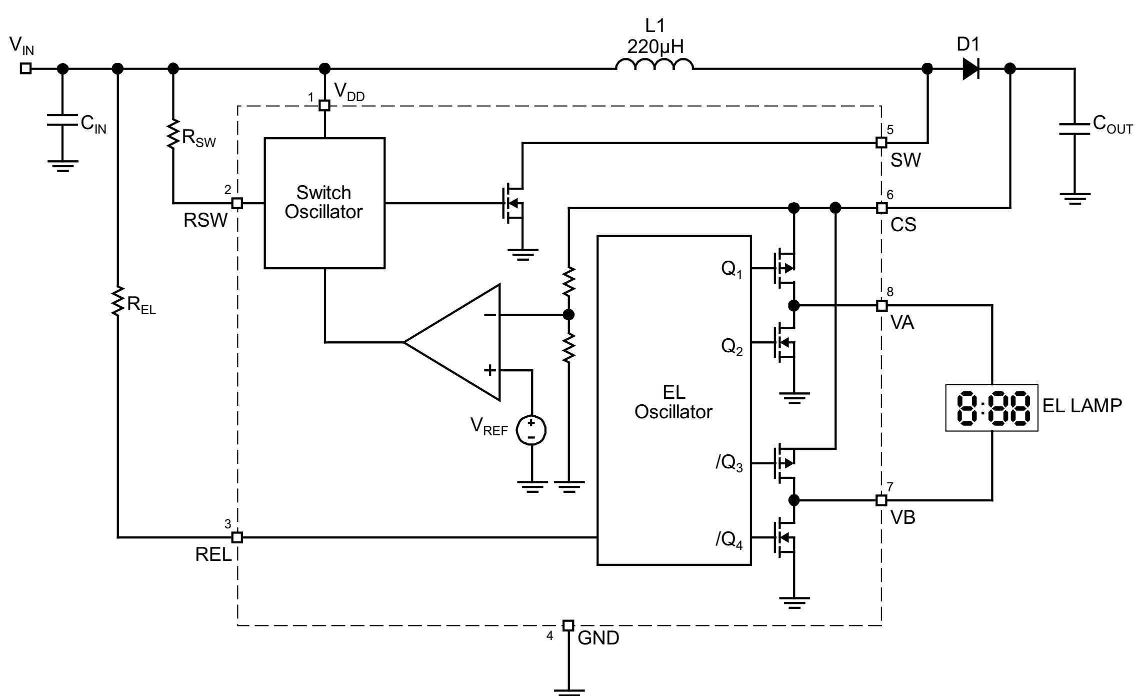
MIC4827
8-Pin MSOP (MM)



Typical Application Circuit



Functional Block Diagram



1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings †

Supply Voltage (V_{DD}) .... –0.5V to +6V
Output Voltage (V_{CS}) .... –0.5V to +100V
Frequency Control Voltage (V_{RSW}, V_{REL}) .... –0.5V to (V_{DD} +0.3V)
Power Dissipation @ T_A = 85°C .... 200 mW
ESD Rating .... (Note 1)

Operating Ratings ‡

Supply Voltage (V_{DD}) .... +1.8V to +5.5V
Lamp Drive Frequency (f_{EL}) .... 60 Hz to 1000 Hz
Switching Transistor Frequency (f_{SW}) .... 8 kHz to 200 kHz

† Notice: Stresses above those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational sections of this specification is not intended. Exposure to maximum rating conditions for extended periods may affect device reliability. Specifications are for packaged product only.

‡ Notice: The device is not guaranteed to function outside its operating ratings.

Note 1: Devices are ESD sensitive. Handling precautions are recommended.

ELECTRICAL CHARACTERISTICS

Electrical Characteristics: V_{IN} = V_{DD} = 3.0V, R_{SW} = 560 kΩ, R_{EL} = 1.0 MΩ.T_A = 25°C unless otherwise noted. **Bold** values indicate –40°C ≤ T_A ≤ +85°C. Note 1

Parameter	Symbol	Min.	Typ.	Max.	Units	Conditions
On-Resistance of Switching Transistor	$R_{DS(ON)}$	—	3.8	**7.0**	Ω	I_{SW} = 100 mA, V_{CS} = 85V
Output Voltage Regulation	V_{CS}	85	90	95	V	V_{DD} = 1.8V to 5.5V
		83	—	**97**	V	—
Output Peak-to-Peak Voltage	V_A-V_B	170	180	190	V	V_{DD} = 1.8V to 5.5V
		166	—	**194**	V	—
Input Low Voltage (Turn Off)	V_{EN-L}	—	—	0.5	V	V_{DD} = 1.8V to 5.5V
Input High Voltage (Turn On)	V_{EN-H}	V_{DD}–0.5	—	—	V	V_{DD} = 1.8V to 5.5V
Shutdown Current (Note 2)	I_{SD}	—	0.01	0.1	µA	R_{SW} = LOW; R_{EL} = LOW V_{DD} = 5.5V
			—	**0.5**		
Input Supply Current	I_{VDD}	—	21	**75**	µA	R_{SW} = HIGH; R_{EL} = HIGH V_{CS} = 85V; V_A, V_B OPEN
Boosted Supply Current	I_{CS}	—	200	**400**	µA	R_{SW} = HIGH; R_{EL} = HIGH V_{CS} = 85V; V_A, V_B OPEN
Input Current Including Inductor Current	I_{IN}	—	28	—	mA	V_{IN} = V_{DD} = 1.8V. See (Figure 1-1)
V_A - V_B Output Drive Frequency	f_{EL}	285	360	435	Hz	—
Switching Transistor Frequency	f_{SW}	53	66	79	kHz	—
Switching Transistor Duty Cycle	D	—	90	—	%	—

Note 1: Specification for packaged product only.
2: Shutdown current is defined as the sum of current going into Pin 1, 5, and 6 when the device is disabled.

TEMPERATURE SPECIFICATIONS (Note 1)

Parameters	Sym.	Min.	Typ.	Max.	Units	Conditions
Temperature Ranges						
Storage Temperature Range	T_S	–65	—	+150	°C	—
Ambient Temperature	T_A	–40	—	+85	°C	—
Package Thermal Resistances						
Thermal Resistance MSOP 8-Ld	θ_{JA}	—	206	—	°C/W	—

Note 1: The maximum allowable power dissipation is a function of ambient temperature, the maximum allowable junction temperature and the thermal resistance from junction to air (i.e., T_A, T_J, θ_{JA}).

Test Circuit

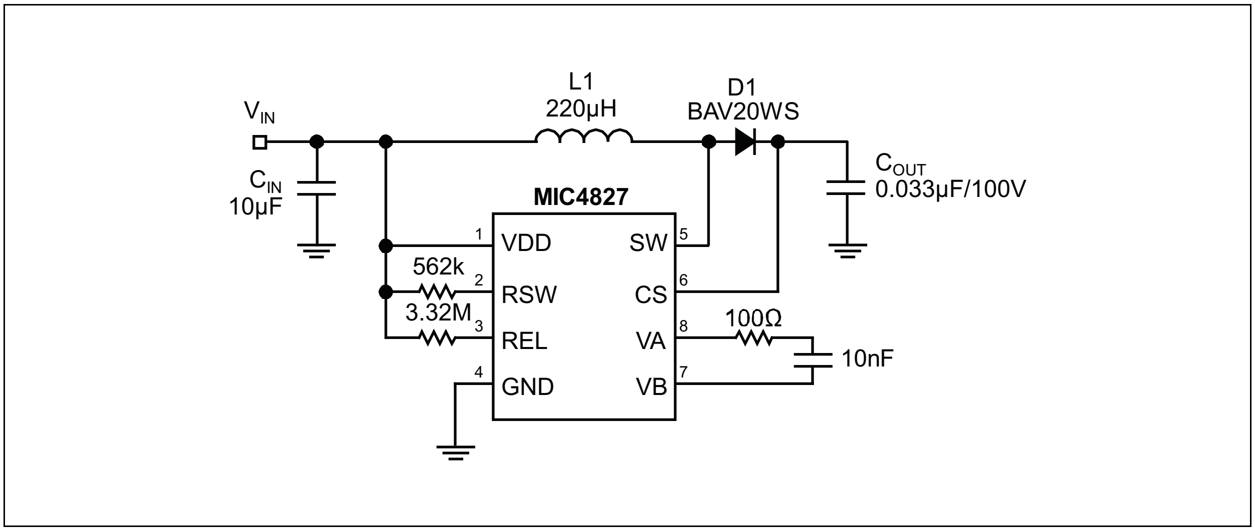


FIGURE 1-1: MIC4827 Test Circuit.

2.0 TYPICAL PERFORMANCE CURVES

Note:	The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

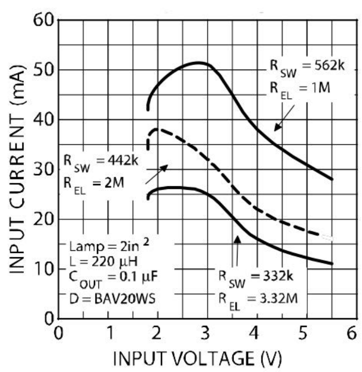


FIGURE 2-1: Total Input Current vs. Input Voltage.

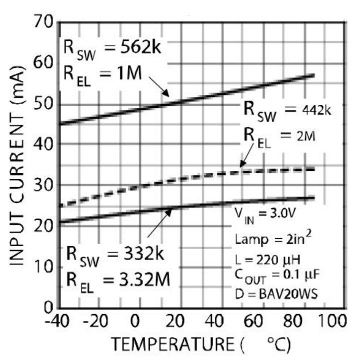


FIGURE 2-2: Total Input Current vs. Temperature.

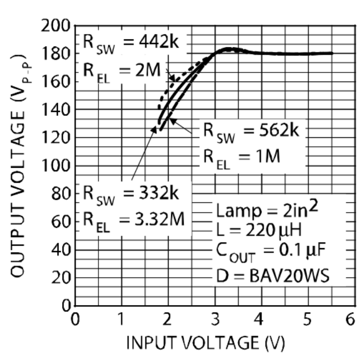


FIGURE 2-3: Output Voltage vs. Input Voltage.

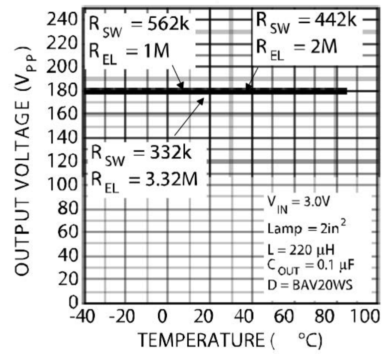


FIGURE 2-4: Output Voltage vs. Temperature.

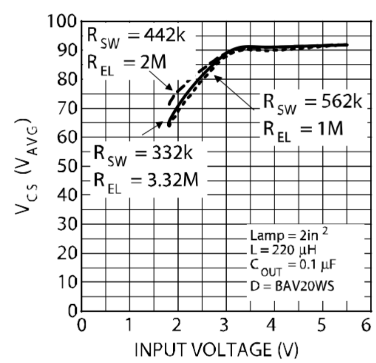


FIGURE 2-5: CS Voltage vs. Input Voltage.

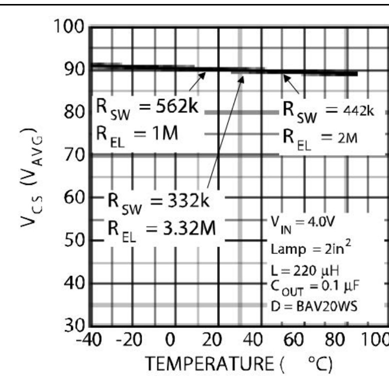


FIGURE 2-6: CS Voltage vs. Temperature.

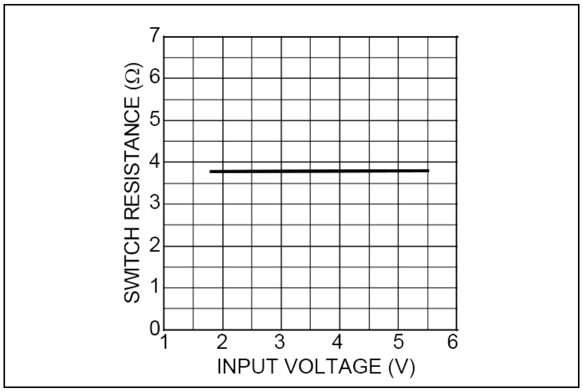


FIGURE 2-7: *Switch Resistance vs. Input Voltage.*

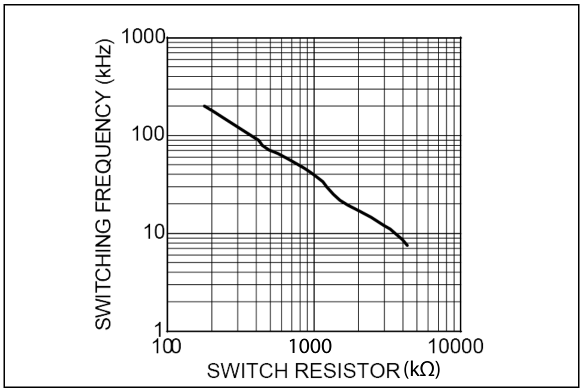


FIGURE 2-8: *Switching Frequency vs. Switch Resistor.*

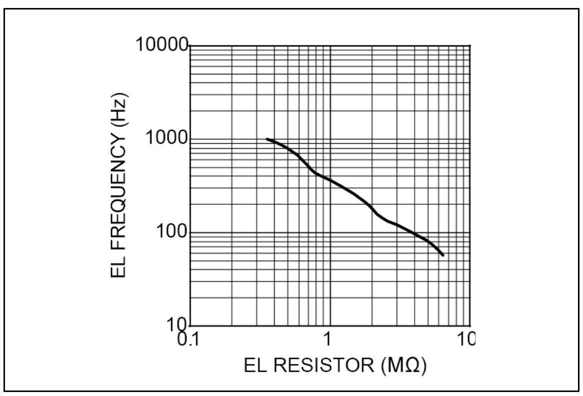


FIGURE 2-9: *EL Frequency vs. EL Resistor.*

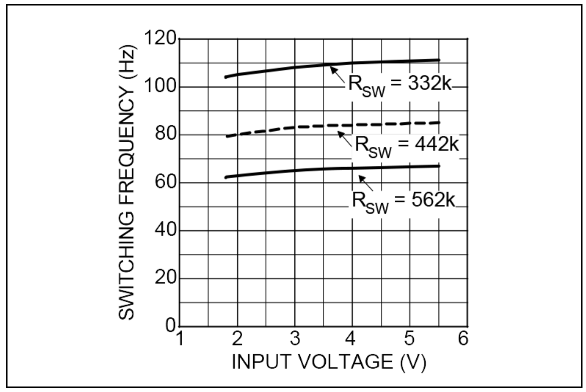


FIGURE 2-10: *Switching Frequency vs. Input Voltage.*

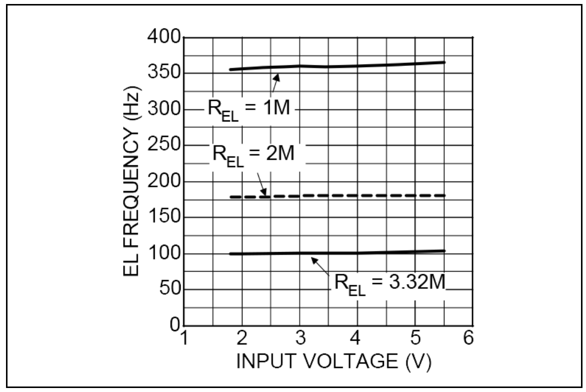


FIGURE 2-11: *EL Frequency vs. Input Voltage.*

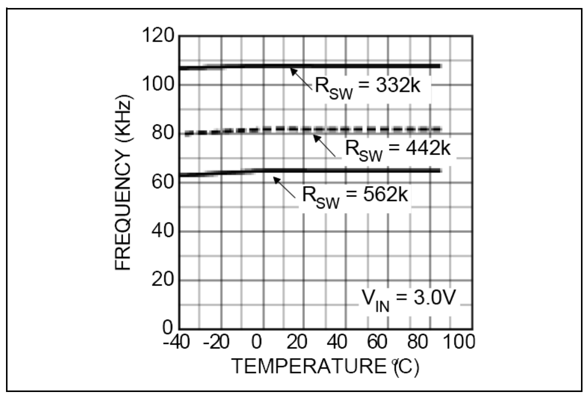


FIGURE 2-12: *Switching Frequency vs. Temperature.*

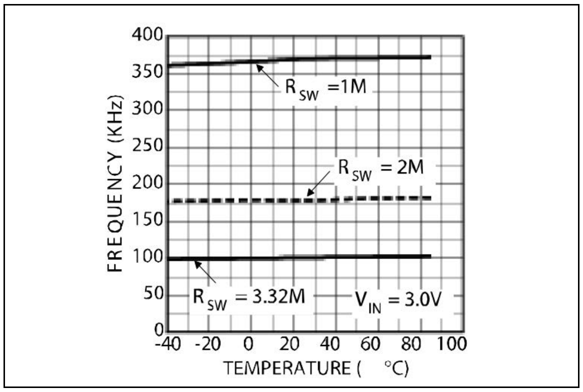


FIGURE 2-13: *EL Frequency vs. Temperature.*

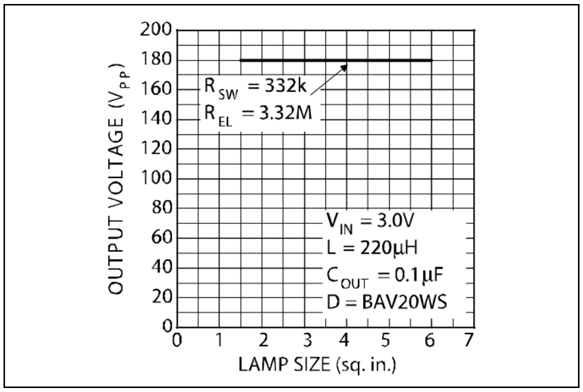


FIGURE 2-14: *Output Voltage vs. Lamp Size.*

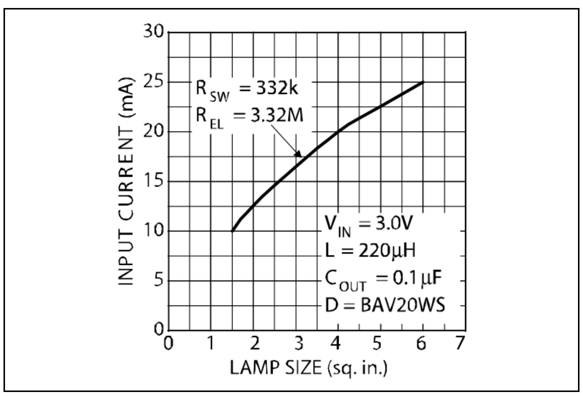


FIGURE 2-15: *Total Input Current vs. Lamp Size.*

3.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in Table 3-1.

TABLE 3-1: PIN FUNCTION TABLE

Pin Number	Pin Name	Description
1	VDD	Supply (Input): 1.8V to 5.5V for internal circuitry.
2	RSW	Switch Resistor (External Component): Set switch frequency of the internal power MOSFET by connecting an external resistor to V_{DD}. Connecting the external resistor to GND disables the switch oscillator and shutdown the device.
3	REL	EL Resistor (External Component): Set EL frequency of the internal H-bridge driver by connecting an external resistor to V_{DD}. Connecting the external resistor to GND disables the EL oscillator.
4	GND	Ground return.
5	SW	Switch Node (Input): Internal high voltage power MOSFET drain.
6	CS	Regulated Boost Output (External Component): Connect to the output capacitor of the boost regulator and connect to the cathode of the diode.
7	VB	EL Output: Connect to one end of the EL lamp. Polarity is not important.
8	VA	EL Output: Connect to the other end of the EL lamp. Polarity is not important.

4.0 FUNCTIONAL DESCRIPTION

4.1 Overview

The MIC4827 is a high voltage EL driver with an AC output voltage of 180V peak-to-peak capable of driving EL lamps up to 6 in^2. Input supply current for the MIC4827 is typically 21 µA with a typical shutdown current of 10 nA. The high voltage EL driver has two internal oscillators to control the switching MOSFET and the H-bridge driver. Both of the internal oscillators' frequencies can be individually programmed through the external resistors to maximize the efficiency and the brightness of the lamps.

4.2 Regulation

Referring to Figure 4-1, initially power is applied to V_{DD}. The internal feedback voltage is less than the reference voltage causing the internal comparator to go low which enables the switching MOSFET's oscillator. When the switching MOSFET turns on, current flows through the inductor and into the switch. The switching MOSFET will typically turn on for 90% of the switching frequency. During the on time, energy is stored in the inductor. When the switching MOSFET turns off, current flowing into the inductor forces the voltage across the inductor to reverse polarity. The voltage across the inductor rises until the external diode conducts and clamps the voltage at $V_{OUT}+V_{D1}$. The energy in the inductor is then discharged into the C_{OUT} capacitor. The internal comparator continues to turn the switching MOSFET on and off until the internal feedback voltage is above the reference voltage. Once the internal feedback voltage is above the reference voltage, the internal comparator turns off the switching MOSFET's oscillator.

When the EL oscillator is enabled, V_A and V_B switch in opposite states to achieve a 180V peak-to-peak AC output signal. The external resistor that connects to the REL pin determines the EL frequency.

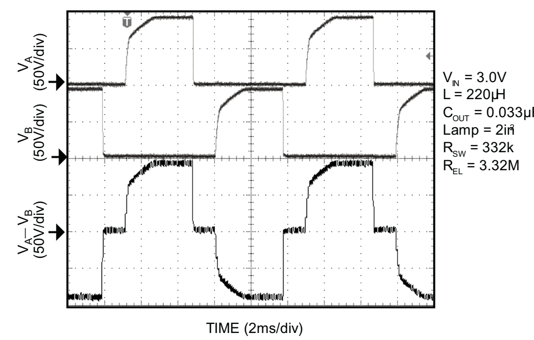


FIGURE 4-1: *108 Hz Typical Output Waveform.*

4.3 Switching Frequency

The switching frequency of the converter is controlled via an external resistor between RSW pin and VDD pin of the device. The switching frequency increases as the resistor value decreases. For resistor value selections, see Figure 2-8 or use equation Equation 4-1. The switching frequency range is 8 kHz to 200 kHz, with an accuracy of ±20%.

EQUATION 4-1:

$$f_{SW}(kHz) = \frac{36}{R_{SW}(M\Omega)}$$

4.4 EL Frequency

The EL lamp frequency is controlled via an external resistor connected between REL pin and VDD pin of the device. As the lamp frequency increases, the resistor value decreases. For resistor value selections, see Figure 2-9 or use equation Equation 4-2. The EL frequency range is 60 Hz to 1000 Hz, with an accuracy of ±20%.

EQUATION 4-2:

$$f_{EL}(Hz) = \frac{360}{R_{EL}(M\Omega)}$$

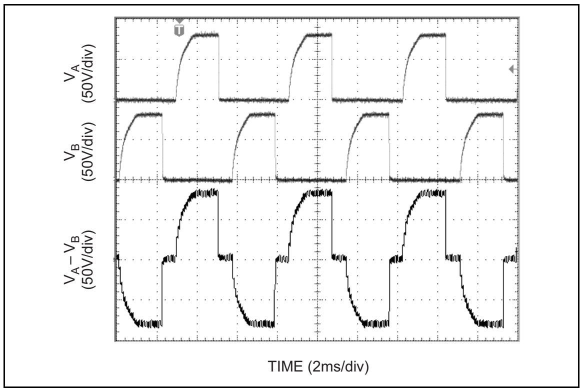


FIGURE 4-2: *180 Hz Output Waveform.*

In general, as the EL lamp frequency increases, the amount of current drawn from the battery will increase. The color of the EL lamp and the intensity are dependent upon its frequency.

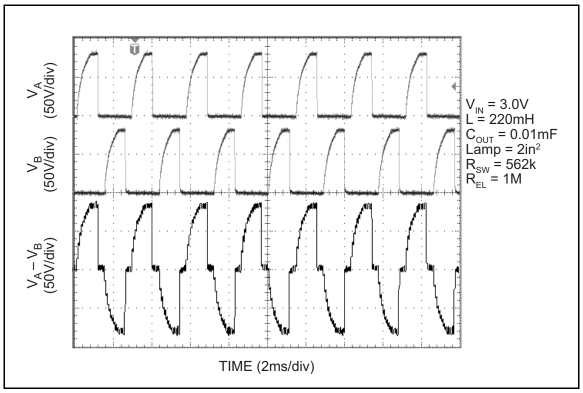


FIGURE 4-3: *360 Hz Output Waveform.*

4.5 Enable Function

The enable function of the MIC4827 is implemented by switching the R_{SW} and R_{EL} resistor between ground and V_{DD}. When R_{SW} and R_{EL} are connected to ground, the switch and the EL oscillators are disabled; therefore the EL driver becomes disabled. When these resistors connect to V_{DD}, both oscillators will function and the EL driver is enabled.

5.0 APPLICATION INFORMATION

5.1 Inductor

In general, smaller value inductors, which can handle more current, are more suitable to drive larger size lamps. As the inductor value decreases, the switching frequency (controlled by R_{SW}) should be increased to avoid saturation or the input voltage should be increased. Typically, inductor values ranging from 220 µH to 560 µH can be used. Murata offers the LQH3C series up to 560 µH and LQH4C series up to 470 µH, with low DC resistance. A 220 µH Murata (LQH4C221K04) inductor is recommended for driving a lamp size of 3 square inches. It has a maximum DC resistance of 4.0Ω.

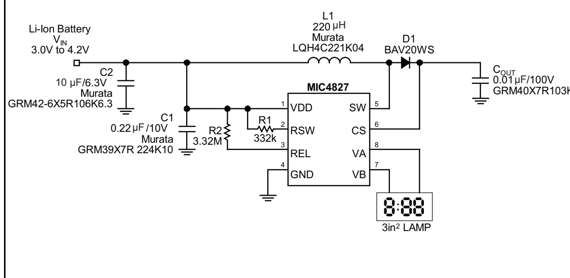
5.2 Diode

The diode must have a high reverse voltage (100V) since the output voltage at the CS pin can reach up to 100V. A fast switching diode with lower forward voltage and higher reverse voltage (100V), such as BAV19WS, can be used to enhance efficiency.

5.3 Output Capacitor

Low ESR capacitors should be used at the regulated boost output (CS pin) of the MIC4827 to minimize the switching output ripple voltage. Selection of the capacitor value will depend upon the peak inductor current, inductor size, and the load. MuRata offers the GRM42-6 series with up to 0.047 µF at 100V, with a X7R temperature coefficient in 1206 surface mount package. Typically, values ranging from 0.01 µF to 0.1 µF at 100V can be used for the regulated boost output capacitor.

5.4 Pre-Designed Application Circuits



V_{IN}	I_{IN}	V_A-V_B	F_{EL}	Lamp Size
3.3V	28 mA	180 V_{PP}	106 Hz	3in^2

FIGURE 5-1: *100 Hz EL Driver for 3in^2 Lamp.*

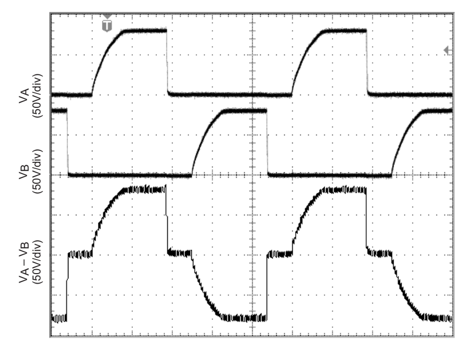
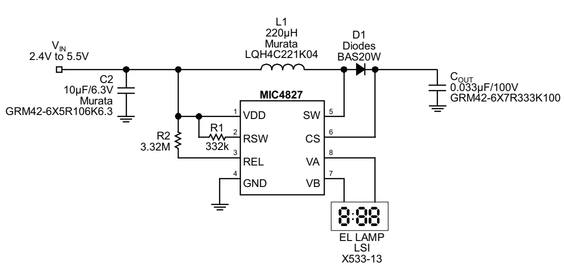
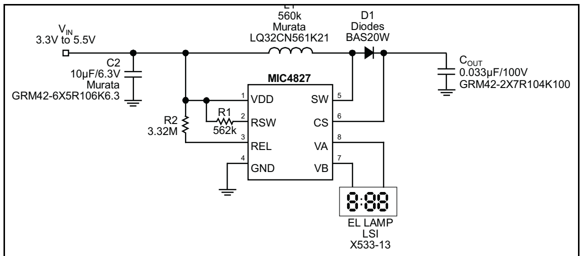


FIGURE 5-2: *Typical Characteristics for 100 Hz EL Driver for 3in^2 Lamp.*



V_{IN}	I_{IN}	V_A-V_B	F_{EL}	Lamp Size
3.3V	18 mA	$180V_{PP}$	104 Hz	$2in^2$

FIGURE 5-3: *EL Driver for $2in^2$ Lamp with C_S = 0.033 µF.*



V_{IN}	I_{IN}	V_A-V_B	F_{EL}	Lamp Size
3.3V	21 mA	$180V_{PP}$	102 Hz	$2in^2$

FIGURE 5-5: *EL Driver for $2in^2$ Lamp with 560 µH Inductor.*

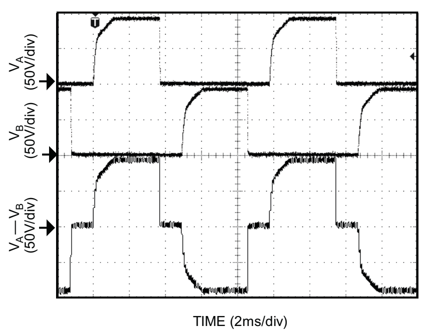


FIGURE 5-4: *Typical Characteristics for EL Driver for $2in^2$ Lamp with C_S = 0.33 µF.*

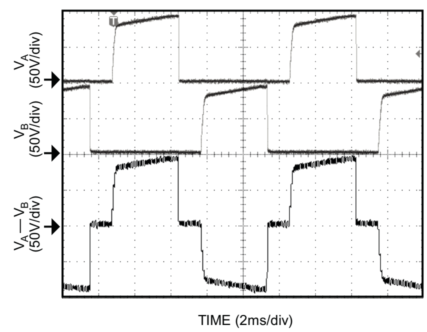
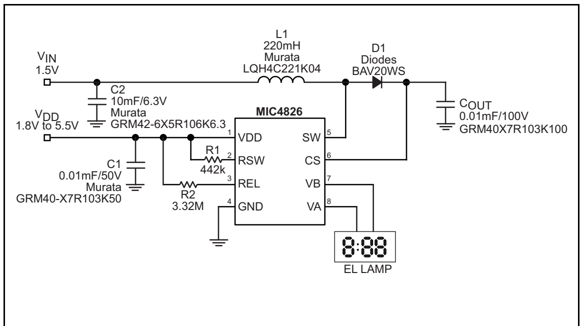


FIGURE 5-6: *Typical Characteristics for EL Driver for $2in^2$ Lamp with 560 µH Inductor.*



V_{IN}	I_{IN}	V_{DD}	I_{DD}	V_A-V_B	F_{EL}	Lamp Size
1.5V	26 mA	3.0V	32 µA	180 V_{PP}	104 Hz	1.6in^2

FIGURE 5-7: *Typical Split Power Supplies Applications.*

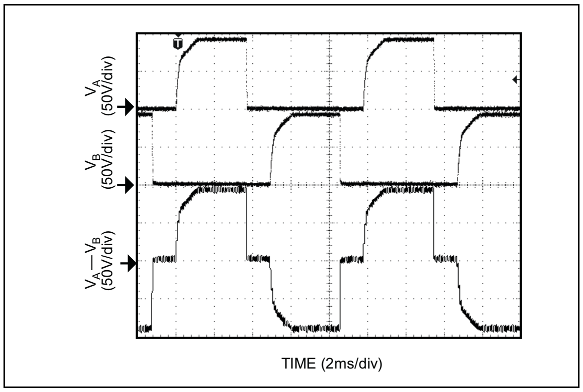
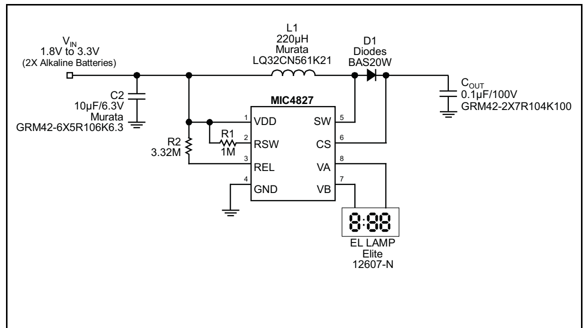


FIGURE 5-8: *Typical Characteristics for Split Power Supplies Applications.*



V_{IN}	I_{IN}	V_A-V_B	F_{EL}	Lamp Size
3.0V	31 mA	180 V_{PP}	104 Hz	5.3in^2

FIGURE 5-9: *EL Driver Remote Control Lamp (Blue Phosphor) Applications.*

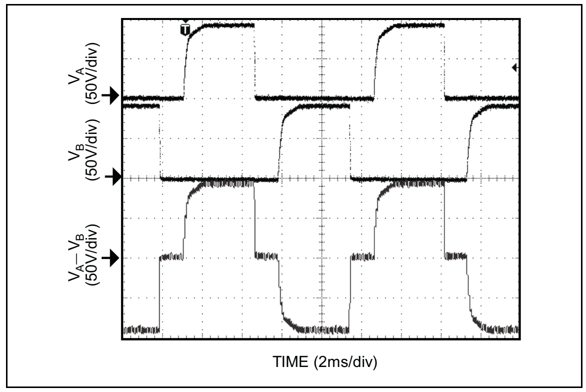
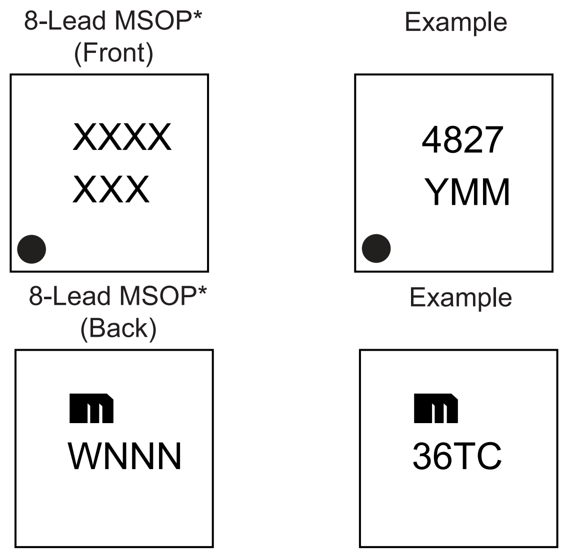


FIGURE 5-10: *Typical Characteristics for EL Driver Remote Control Lamp (Blue Phosphor) Applications.*

6.0 PACKAGING INFORMATION

6.1 Package Marking Information



Legend:	XX...X	Product code or customer-specific information
	Y	Year code (last digit of calendar year)
	YY	Year code (last 2 digits of calendar year)
	WW	Week code (week of January 1 is week '01')
	NNN	Alphanumeric traceability code
	(e3)	Pb-free JEDEC® designator for Matte Tin (Sn)
	*	This package is Pb-free. The Pb-free JEDEC designator ((e3)) can be found on the outer packaging for this package.
	●, ▲, ▼	Pin one index is identified by a dot, delta up, or delta down (triangle mark).

Note: In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for customer-specific information. Package may or may not include the corporate logo.

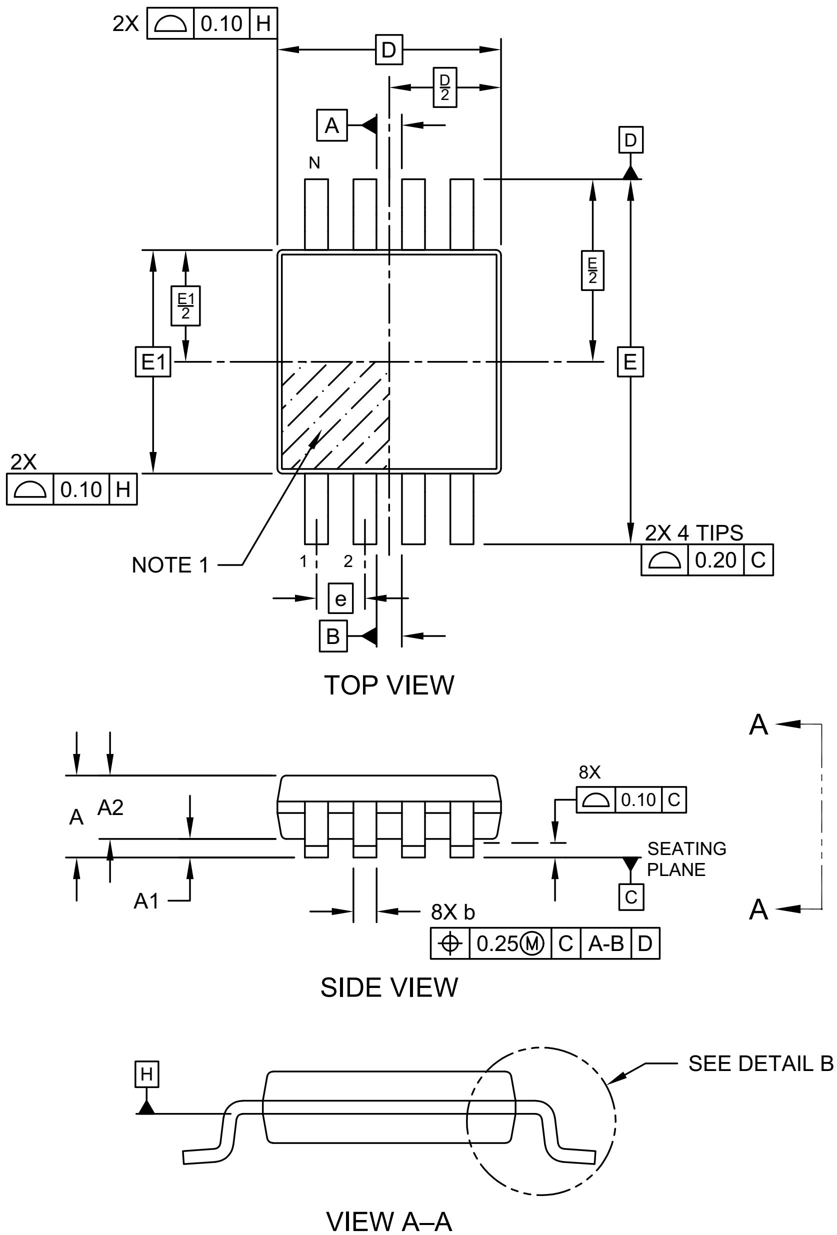
Underbar (_) and/or Overbar (‾) symbol may not be to scale.

Note: If the full seven-character YYWWNNN code cannot fit on the package, the following truncated codes are used based on the available marking space:
6 Characters = YWWNNN; 5 Characters = WWNNN; 4 Characters = WNNN; 3 Characters = NNN;
2 Characters = NN; 1 Character = N

8-Lead MSOP Package Outline and Recommended Land Pattern

8-Lead Plastic Micro Small Outline Package (DMA) - 3x3 mm Body [MSOP]
Micrel Legacy Package MSOP-08L

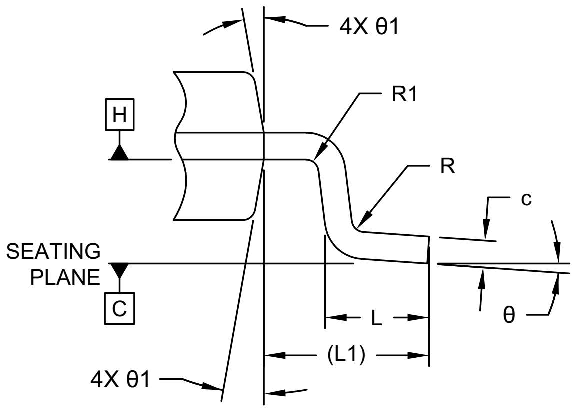
Note:	For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



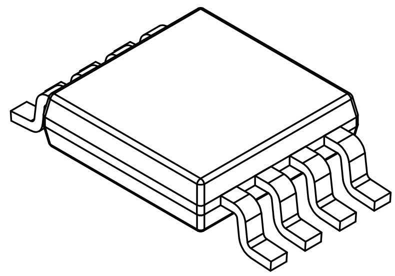
Microchip Technology Drawing C04-1082 Rev A Sheet 1 of 2

8-Lead Plastic Micro Small Outline Package (DMA) - 3x3 mm Body [MSOP]
Micrel Legacy Package MSOP-08L

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



DETAIL B



Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Number of Terminals	N		8	
Pitch	e		0.65 BSC	
Overall Height	A	0.94	1.02	1.10
Standoff	A1	0.00	–	0.15
Molded Package Thickness	A2	0.75	0.85	0.95
Overall Length	D		3.00 BSC	
Overall Width	E		4.90 BSC	
Molded Package Width	E1		3.00 BSC	
Terminal Width	b	0.25	0.30	0.40
Terminal Thickness	c	0.13	0.15	0.23
Terminal Length	L	0.45	0.55	0.70
Footprint	L1		0.95 REF	
Lead Bend Radius	R	0.07	–	–
Lead Bend Radius	R1	0.07	–	–
Foot Angle	θ	0°	–	8°
Mold Draft Angle	θ1	5°	–	15°

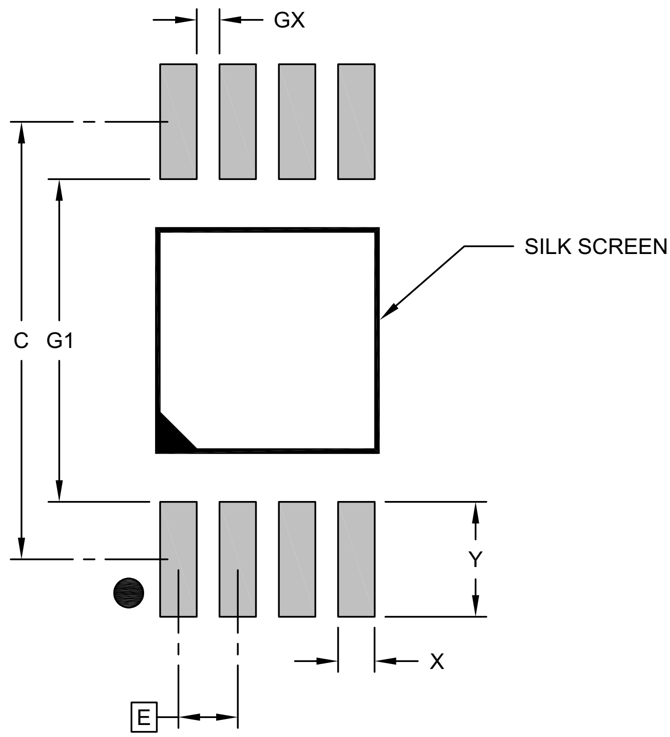
Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.
2. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15mm per side.
3. Dimensioning and tolerancing per ASME Y14.5M
   BSC: Basic Dimension. Theoretically exact value shown without tolerances.
   REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-1082 Rev A Sheet 2 of 2

8-Lead Plastic Micro Small Outline Package (DMA) - 3x3 mm Body [MSOP]
Micrel Legacy Package MSOP-08L

Note:	For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Contact Pitch	E	0.65 BSC		
Contact Pad Spacing	C		4.80	
Contact Pad Width (X8)	X			0.40
Contact Pad Length (X8)	Y			1.26
Contact Pad to Contact Pad (X4)	G1	3.54		
Contact Pad to Contact Pad (X6)	GX	0.25		

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M
   BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-3082 Rev A

NOTES:

APPENDIX A: REVISION HISTORY

Revision A (August 2022)

- Converted Micrel document MIC4827 to Microchip data sheet DS20006708A.
- Minor text changes throughout.

NOTES:

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, contact your local Microchip representative or sales office.

PART NO.	X	XX	–XX
Device	Junction Temperature Range	Package	Media Type

Device:	MIC4827:	Low Input Voltage, 180 V_{PP} Output Voltage, EL Driver
Junction Temperature Range:	Y =	–40°C to +85°C, Industrial
Package:	MM =	8-Lead MSOP
Media Type:	<blank> =	100/Tube
	TR =	2,500/Reel

Examples:

a) MIC4827YMM: Low Input Voltage, 180 V_{PP} Output Voltage, EL Driver, –40°C to +85°C Temperature Range, 8-Lead MSOP Package, 100/Tube

b) MIC4827YMM-TR: Low Input Voltage, 180 V_{PP} Output Voltage, EL Driver, –40°C to +85°C Temperature Range, 8-Lead MSOP Package, 2,500/Reel

Note 1: Tape and Reel identifier only appears in the catalog part number description. This identifier is used for ordering purposes and is not printed on the device package. Check with your Microchip Sales Office for package availability with the Tape and Reel option.

NOTES:

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